2-Bit Bus Switch

The 7WB3305 is an advanced high-speed low-power 2-bit bus switch in ultra-small footprints.

Features

- High Speed: $t_{PD} = 0.25$ ns (Max) @ $V_{CC} = 4.5$ V
- 3 Ω Switch Connection Between 2 Ports
- Power Down Protection Provided on Inputs
- Zero Bounce
- TTL-Compatible Control Inputs
- Ultra–Small Pb–Free Packages
- These are Pb–Free Devices



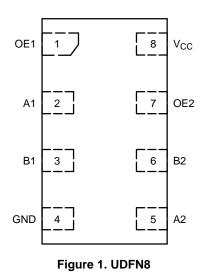
ON Semiconductor®

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		MARKING DIAGRAMS
	UDFN8 MU SUFFIX CASE 517AJ	AMM ○ ■
	Micro8™ DM SUFFIX CASE 846A	8 11 11 3305 AYW- O 1 11111
	UDFN8 1.95 x 1.0 CASE 517CA	х м •
A Y W M •	= Assembly Loc = Year = Work Week = Date Code = Pb-Free Pack rodot may be in eithe	kage
	bast may be in enne	

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



(Top Thru–View)

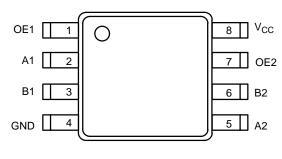


Figure 2. Micro8 (Top View)

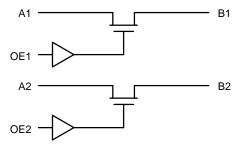


Figure 3. Logic Diagram

FUN	CTION	TABLE
1 014		IADEE

Input OEn	Function
L	Disconnect
Н	Bn = An

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit V	
V _{CC}	DC Supply Voltage	-0.5 to +7.0		
V _{IN}	Control Pin Input Voltage	-0.5 to +7.0	V	
V _{I/O}	Switch Input / Output Voltage	-0.5 to +7.0	V	
۱ _{IK}	Control Pin DC Input Diode Current V _{IN} < GND	-50	mA	
Ι _{ΟΚ}	Switch I/O Port DC Diode Current V _{I/O} < GND	-50	mA	
Ι _Ο	ON-State Switch Current	±128	mA	
	Continuous Current Through V _{CC} or GND	± 150	mA	
I _{CC}	DC Supply Current Per Supply Pin	± 150	mA	
I _{GND}	DC Ground Current per Ground Pin	± 150	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C	
TJ	Junction Temperature Under Bias	150	°C	
θ_{JA}	Thermal Resistance UDFN8 (Note 1) Micro8	111 392	°C/W	
PD	Power Dissipation in Still Air at 85°C UDFN8 Micro8	1127 319	mW	
MSL	Moisture Sensitivity	Level 1		
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in		
V _{ESD}	ESD Withstand Voltage Human Body Mode (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V	
ILATCHUP	Latchup Performance Above V _{CC} and Below GND at 125°C (Note 5)	±200	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD22-A114-A.

3. Tested to EIA / JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	4.0	5.5	V	
V _{IN}	Control Pin Input Voltage	0	5.5	V	
V _{I/O}	Switch Input / Output Voltage	0	5.5	V	
T _A	Operating Free–Air Temperature	-55	+125	°C	
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate	Control Input Switch I/O	0 0	5 DC	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

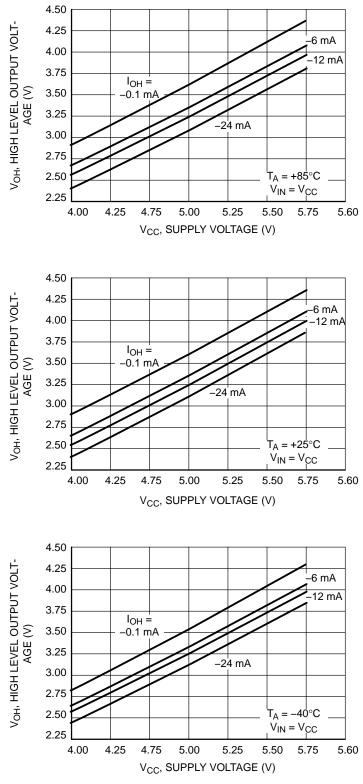
		Vcc		T _A = 25°C			T _A = -55°C to +125°C		
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Unit
V _{IK}	Clamp Diode Voltage	I _{I/O} = -18 mA	4.5			-1.2		-1.2	V
V _{IH}	High–Level Input Voltage (Control)		4.0 to 5.5	2.0			2.0		V
V _{IL}	Low–Level Input Voltage (Control)		4.0 to 5.5			0.8		0.8	V
V _{OH}	Output Voltage High	See Figure 4							
I _{IN}	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±0.1		±1.0	μΑ
I _{OFF}	Power Off Leakage Current	$V_{I/O} = 0$ to 5.5 V	0			±0.1		±1.0	μΑ
Icc	Quiescent Supply Current	I _O = 0, V _{IN} = V _{CC} or 0 V	5.5			±0.1		±1.0	μΑ
ΔI_{CC}	Increase in Supply Current (Control Pin)	One input at 3.4 V; Other inputs at V_{CC} or GND	5.5					2.5	mA
R _{ON}	Switch ON Resistance	V _{I/O} = 0, I _{I/O} = 64 mA I _{I/O} = 30 mA	4.5		3 3	7 7		7 7	Ω
		$V_{I/O} = 2.4,$ $I_{I/O} = 15 \text{ mA}$			6	15		15	
		V _{I/O} = 2.4, I _{I/O} = 15 mA	4.0		10	20		20	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

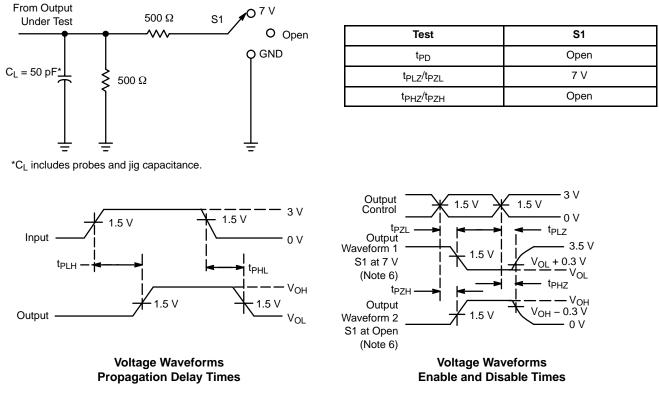
			v _{cc}	Υ _A = 25 °C		T _A = −55°C to +125°C			
Symbol	Parameter	Test Condition	(V)	Min	Тур	Max	Min	Max	Unit
t _{PD}	Propagation Delay, Bus to Bus	See Figure 5	4.0 to 5.5			0.25		0.25	ns
t _{EN}	Output Enable Time	See Figure 5	4.5 to 5.5	0.8	2.5	4.2	0.8	4.2	ns
			4.0	0.8	3.0	4.6	0.8	4.6	
t _{DIS}	Output Disable Time		4.5 to 5.5	0.8	3.0	4.8	0.8	4.8	ns
			4.0	0.8	2.9	4.4	0.8	4.4	
C _{IN}	Control Input Capacitance	V _{IN} = 5 or 0 V	5.0		2.5				pF
C _{IO(ON)}	Switch On Capacitance	Switch ON	5.0		10				pF
C _{IO(OFF)}	Switch Off Capacitance	Switch OFF	5.0		5				pF

TYPICAL DC CHARACTERISTICS





AC LOADING AND WAVEFORMS



Parameter Measurement Information

6. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control

7. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns. 8. The outputs are measured one at a time, with one transition per measurement.

9. t_{PLZ} and t_{PHZ} are the same as t_{DIS}.

10. t_{PZL} and t_{PZH} are the same as t_{EN} . 11. t_{PHL} and t_{PLH} are the same as t_{PD} .

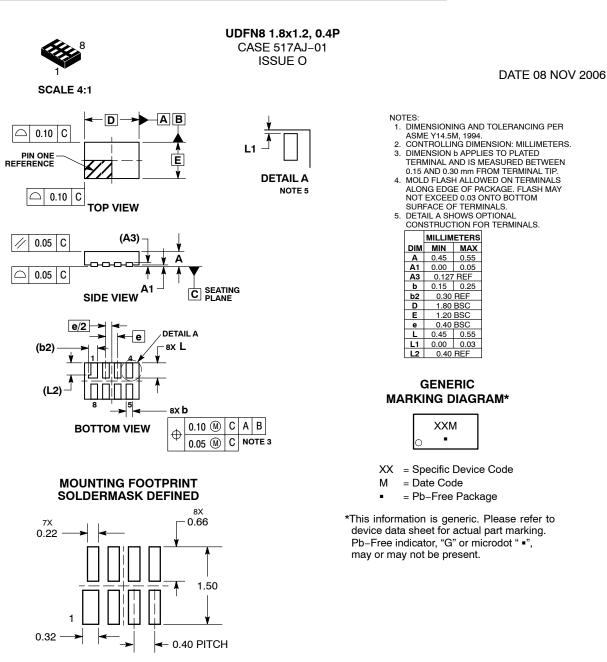


ORDERING INFORMATION

Device	Package	Shipping [†]
7WB3305MUTAG	UDFN8 (Pb-Free)	3000 / Tape & Reel
7WB3305DMR2G	Micro8 (Pb-Free)	4000 / Tape & Reel
7WB3305DMUTCG	UDFN8, 1.95 x 1.0, 0.5 mm Pitch (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





DIMENSIONS: MILLIMETERS

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